## NSN 5961-01-013-4908

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-013-4908 **Inclosure Material:** Metal **Overall Length:** 1.010 inches **Overall Height:** 0.275 inches **Overall Width:** 0.510 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 175.0 collector to base voltage/static/emitter open and 175.0 collector to emitter voltage/static/base open and 5.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 8.6 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Precious Material And Location:** Terminals external surfaces gold **Precious Material:** Gold **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a

No

**Unit Of Measure:** 

Demilitarization:

## **NSN 5961-01-013-4908** Transistor - Page 2 of 2



Fiig:

A110a0